## What is claimed is:

1. A thin film transistor substrate in a liquid crystal display provided with a data lines for applying a data signals, a gate line for applying a gate signal, and a pixel electrode for driving a liquid crystal cell, said substrate comprising:

a gate dummy pattern formed in such a manner to be extended in the vertical direction from the gate line and to overlap with the data line and the pixel electrode.

- 2. The thin film transistor substrate according to claim 1, wherein the gate dummy pattern is formed in such a manner to overlap with one side or both sides of the data line and the edge of the pixel electrode adjacent thereto.
- 3. The thin film transistor substrate according to claim 2, wherein the gate dummy pattern is used as a redundancy electrode for electrically connecting the gate line to the broken data line.
- 4. The thin film transistor substrate according to claim 3, wherein the gate dummy pattern includes a hole connected to the gate line and formed to permit a repair.
- 5. The thin film transistor substrate according to claim 1, wherein the gate dummy pattern is used as a black matrix.
- 30 6. The thin film transistor substrate according to claim 1, further comprising:
  - a storage capacitor defined by a horizontal overlapping part between the gate line and the pixel

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- 7. The thin film transistor substrate according to claim
- 4, further comprising:
- a protrusion formed in such a manner to overlap with the hole, thereby shutting off a light leaked between the gate dummy pattern and the gate line.

and No